

C106 Series



Description

Glassivated PNPN devices designed for high volume consumer applications such as temperature, light, and speed control; process and remote control, and warning systems where reliability of operation is important.

Features

- Glassivated Surface for Reliability and Uniformity
- Power Rated at Economical Prices
- Practical Level Triggering and Holding Characteristics
- Flat, Rugged, Thermopad Construction for Low Thermal Resistance, High Heat Dissipation and Durability

Po

- Sensitive Gate Triggering
- These are Pb–Free
 Devices

Functional Diagram



Additional Information



Datasheet



Samples

Pin Out



Additional Information

Maximum Ratings (T = 25°C unless otherwise noted)

v . j				
Rating	Symbol	Value	Unit	
Peak Repetitive Off-State Voltage (Sine Wave, 50-60 Hz, RGK = 1 K, TC = -40° to 110°C)	C106B C106D, C106D1* C106M	V _{drm} , V _{rrm}	200 400 600	V
On-State RMS Current (180° Conduction Angles, TC = 80°C)		I _{T (RMS)}	4.0	А
Average On–State Current (180° Conduction Angles, $T_c = 80$ °C)	I _{T(AV)}	2.55	А	
Peak Non-Repetitive Surge Current (1/2 Cycle, Sine Wave, 60 Hz, T _J = +25°C)	I _{TSM}	20	А	
Circuit Fusing Considerations (t = 8.3 ms)	l²t	1.65	A2s	
Forward Peak Gate Current (Pulse Width 1.0 sec, TC = 80°C)	I _{GM}	0.2	А	
Forward Peak Gate Power (Pulse Width \leq 1.0 $\mu sec, T_{_{\rm C}}$ = 80°C)	P _{GM}	0.5	W	
Forward Average Gate Power (Pulse Width \leq 1.0 $\mu sec,T_{_C}$ = 80°C)	P _{G(AV)}	0.1	W	
Operating Junction Temperature Range	TJ	-40 to +110	°C	
Storage Temperature Range	T _{stg}	-40 to +150	°C	
Mounting Torque (Note 2)	_	6.0	in. lb.	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the

Recommended Operating Conditions may affect device reliability.
1. V_{PRM} and V_{RRM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

2. Torque rating applies with use of torque washer (Shakeproof WD19523 or equivalent). Mounting Torque in excess of 6 in. Ib. does not appreciably lower case-to-sink thermal resistance. Main terminal 2 and heat-sink contact pad are common.

Thermal Characteristics							
Rating		Symbol	Value	Unit			
Thermal Resistance,	Junction-to-Case (AC) Junction-to-Ambient	R _{ejc} R _{eja}	3.0 75	°C/W			
Maximum Lead Temperature for Soldering Pur 10 seconds	TL	260	°C				

Electrical Characteristics - OFF (T_j = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Тур	Мах	Unit
Peak Repetitive Forward or Reverse Blocking Current	$T_{J} = 25^{\circ}C$	I _{drm} , I _{rrm}	-	-	10	μΑ
$(V_{AK} = Rated V_{DRM} \text{ or } V_{RRM'} R_{GK} = 1 \Omega k)$	$T_{J} = 110^{\circ}C$		-	-	100	μA

Electrical Characteristics - **ON** ($T_{J} = 25^{\circ}C$ unless otherwise noted)

Characteristic			Min	Тур	Мах	Unit
Peak Forward On-State Voltage (Note 3) ($I_{TM} = 4 A$)		V _{TM}	-	-	2.2	V
Gate Trigger Current (Continuous dc)	$T_J = 25^{\circ}C$		-	15	200	
$(V_{_{D}} = 12 \text{ V}, \text{ R}_{_{L}} = 100 \Omega, \text{ All Quadrants})$	$T_{J} = -40^{\circ}C$	GT	-	35	500	μA
Peak Reverse Gate Voltage ($I_{GR} = 10 \ \mu A$)		V _{GRM}	-	-	6.0	V
Gate Trigger Voltage (Continuous dc) ($V_p = 12$ Vdc, $R_L = 100 \Omega$, $T_c = 25^{\circ}C$)	$T_J = 25^{\circ}C$	V	0.4	0.60	0.8	V
	$T_{J} = -40^{\circ}C$	V _{GT}	0.5	0.75	1.0	
Gate Non-Trigger Voltage (Continuous dc) (Note 4) (V _{AK} = 12 V, R _L = 100 (VAK = 12 V, RL = 100 , TJ = 110°C), T _J = 110°C)		V _{gD}	0.2	-	_	V
Latching Current	$T_J = 25^{\circ}C$	1	-	0.20	5.0	
$(V_{AK} = 12 \text{ V}, \text{ I}_{g} = 20 \text{ mA}, \text{ R}_{gK} = 1 \text{ k}\Omega)$	$T_{J} = -40^{\circ}C$	i_	-	0.35	7.0	mA
Holding Current	T _J = 25°C		-	0.19	3.0	
$(V_p = 12 \text{ Vdc})$	$T_{J} = -40^{\circ}C$	I _H	-	0.33	6.0	mA
(Initiating Current = 20 mA, $R_{gK} = 1 k\Omega$)	$T_{J} = +110^{\circ}C$		_	0.07	2.0	1



Dynamic Characteristics					
Characteristic	Symbol	Min	Тур	Max	Unit
Critical Rate-of-Rise of Off State Voltage (V_{AK} = Rated V_{DRM} , Exponential Waveform, R_{GK} = 1k Ω , T_{J} = 110°C)	dv/dt	-	8.0	-	V/µs

3. Pulse Test: Pulse Width \leq 2.0 ms, Duty Cycle \leq 2%. **4.** R_{_{GK}} is not included in measurement.

Voltage Current Characteristic of SCR

Symbol	Parameter
V _{DRM}	Peak Repetitive Forward Off State Voltage
I	Peak Forward Blocking Current
V _{RRM}	Peak Repetitive Reverse Off State Voltage
I _{RRM}	Peak Reverse Blocking Current
V _{TM}	Maximum On State Voltage
I _H	Holding Current





Figure 1. Average Current Derating



Figure 3. Typical Gate Trigger Current vs. Junction Temp



Figure 2. Maximum On-State Power Dissipation



Figure 4. Typical Holding Current vs. Junction Temp



Figure 5. Typical Latching Current vs. Junction Temp



Figure 5. Typical Gate Trigger Voltage vs. Junction Temp





Dimensions



Part Marking System



Dim	Inc	hes	Millimeters		
UIM	Min	Max	Min	Max	
Α	0.102	0.110	2.60	2.80	
A1	0.047	0.055	1.20	1.40	
b	0.028	0.034	0.70	0.86	
b2	0.028	0.034	0.70	0.86	
С	0.019	0.022	0.49	0.57	
D	0.417	0.449	10.60	11.40	
E	0.291	0.323	7.40	8.20	
е	0.090 TYP		2.29 TYP		
L	0.551	0.630	14.00	16.00	
L1	0.091	0.106	2.30	2.70	
Р	0.118	0.134	3.00	3.40	
٥	0.142	0.157	3.60	4.00	
b1	0.047	0.055	1.2	1.4	

1	DIMENSIONING	AND TO	ERANCING P	PER ANSI Y14 5M	1982

2. CONTROLLING DIMENSION: INCH.

3. 077-01 THRU -08 OBSOLETE, NEW STANDARD 077-09.

Pin Assignment				
1	Cathode			
2	Anode			
3	Gate			

Ordering Information						
Device	Package	Shipping				
C106BG	-					
C106DG						
C106D1G*	TO225AA	2500 Units/Box				
C106MG	(Pb-Free)					
C106M1G*						
C106MTG		60 Units/Tube 1920 Units/Box				

*D1 signifies European equivalent for D suffix and M1 signifies European equivalent for M suffix.

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